# LSIC2SD065D16A 650 V, 16 A SiC Schottky Barrier Diode









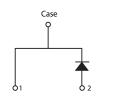
### **Description**

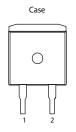
This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

#### **Features**

- AEC-Q101 qualified
- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- · Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

### Circuit Diagram TO-263-2L





### **Applications**

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- Solar inverters
- Industrial motor drives
- EV charging stations

#### **Environmental**

- Littelfuse "RoHS" logo = RoHS RoHS conform
- Littelfuse "HF" logo = **HF** Halogen Free
- Littelfuse "Pb-free" logo = Po Pb-free lead plating

#### **Maximum Ratings**

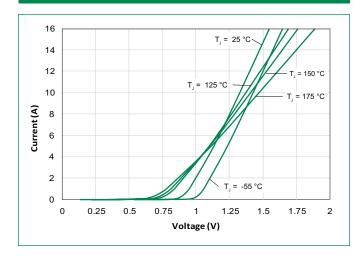
Characteristics	Symbol	Conditions	Value	Unit	
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	-	650	V	
DC Blocking Voltage	V <sub>R</sub>	T <sub>J</sub> = 25 °C	650	V	
Continuous Forward Current		T <sub>C</sub> = 25 °C	38	А	
	l <sub>F</sub>	T <sub>C</sub> = 135 °C	17.2		
		T <sub>C</sub> = 140 °C	16		
Non-Repetitive Forward Surge Current	I <sub>FSM</sub>	$T_C = 25  ^{\circ}\text{C}, T_P = 10  \text{ms},  \text{Half sine pulse}$	70	А	
Power Dissipation	P <sub>Tot</sub>	T <sub>C</sub> = 25 °C	125	W	
		T <sub>C</sub> = 110 °C	54	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	
Operating Junction Temperature	T <sub>J</sub>	-	-55 to 175	°C	
Storage Temperature	T <sub>STG</sub>	-	-55 to 150	°C	
Soldering Temperature	T <sub>SOLD</sub>	-	260	°C	

### Electrical Characteristics (T, = 25 °C unless otherwise specified)

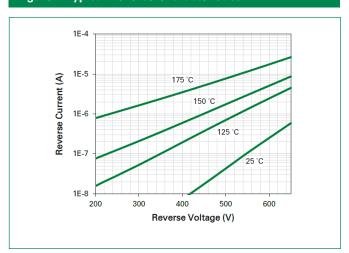
			Value			
Characteristics	istics Symbol Conditions	Conditions	Min.	Тур.	Max.	Unit
Forward Voltage V <sub>F</sub>	\/	I <sub>F</sub> = 16 A, T <sub>J</sub> = 25 °C	-	1.5	1.8	V
	V <sub>F</sub>	I <sub>F</sub> = 16 A, T <sub>J</sub> = 175 °C	-	1.85	-	
Reverse Current	I <sub>R</sub>	$V_{R} = 650  \text{V}$ , $T_{J} = 25  ^{\circ}\text{C}$	-	<1	50	μΑ
		$V_{_{\rm R}} = 650  \text{V}, T_{_{\rm J}} = 175  ^{\circ}\text{C}$	-	55	-	
Total Capacitance C		$V_R = 1 V, f = 1 MHz$	-	730	-	pF
	С	$V_R = 200  V$ , $f = 1  MHz$	-	92	-	
		$V_R = 400  \text{V},  \text{f} = 1  \text{MHz}$	-	66	-	
Total Capacitive Charge	Q <sub>c</sub>	$V_{R} = 400 \text{ V}, \ \ Q_{c} = \int\limits_{0}^{V_{R}} c(v) dv$	-	48	-	nC

Thermal Characteristics				
Characteristics	Symbol	Value	Unit	
Thermal Resistance	R <sub>esc</sub>	1.2	°C/W	

Figure 1: Typical Foward Characteristics



**Figure 2: Typical Reverse Characteristics** 





**Figure 3: Power Derating** 

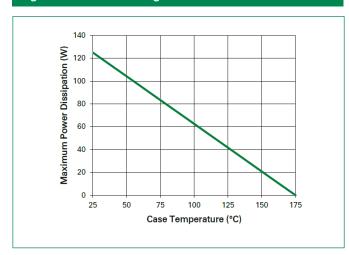


Figure 4: Current Derating

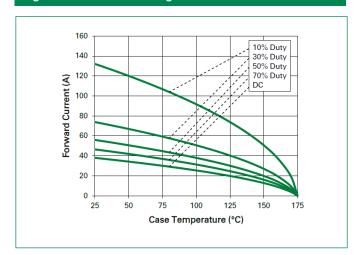


Figure 5: Capacitance vs. Reverse Voltage

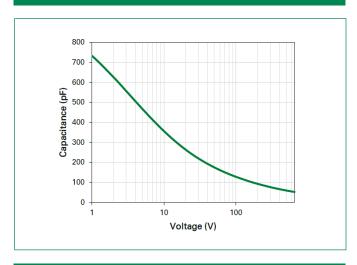


Figure 6: Capacitive Charge vs. Reverse Voltage

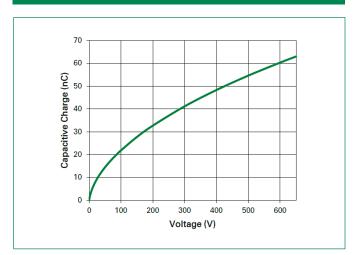


Figure 7: Stored Energy vs. Reverse Voltage

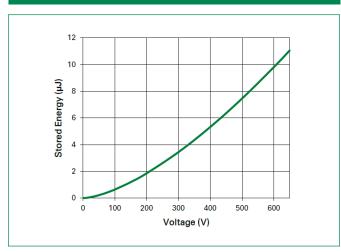
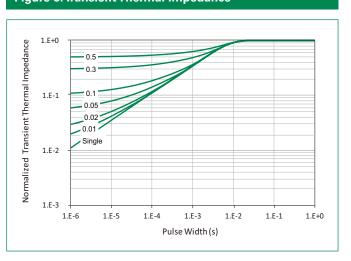
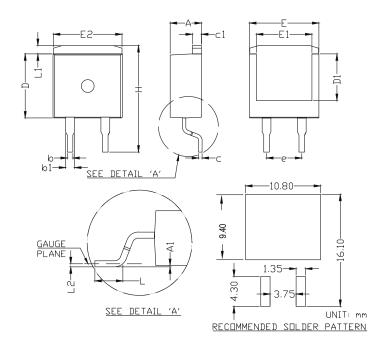


Figure 8: Transient Thermal Impedance

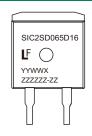


### Dimensions-Package TO-263-2L



Cumbal	Millimeters			
Symbol	Min	Nom	Max	
А	4.30	4.50	4.70	
A1	0.00	-	0.25	
b	0.70	0.80	0.90	
b1	1.17	1.27	1.37	
С	0.46	0.50	0.60	
c1	1.25	1.30	1.40	
D	9.00	9.20	9.40	
D1	6.50	6.70	6.90	
E	9.80	10.00	10.20	
E1	7.80	8.00	8.20	
E2	9.70	9.90	10.10	
е	5.08 BSC			
Н	15.00	15.30	15.60	
L	2.00	2.30	2.60	
L1	1.00	1.20	1.40	
L2	0.254 BSC			

# Part Numbering and Marking System



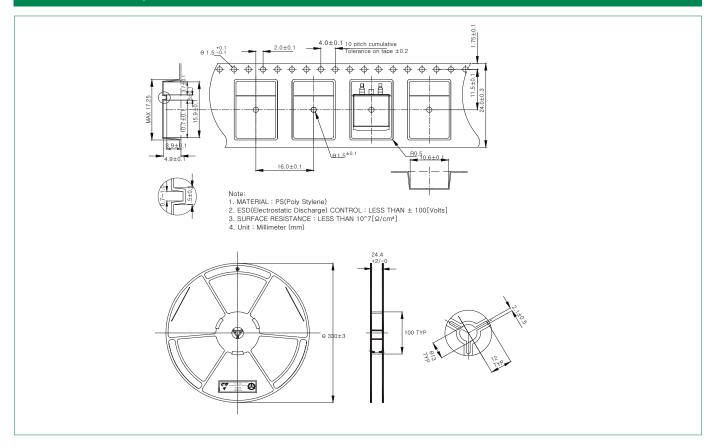
SIC	= SiC Diode
2	= Gen2
SD	= Schottky Diode
065	= Voltage Rating (650 V)
D	= TO-263 Package (2 Lead)
16	= Current Rating (16 A)
YY	= Year
WW	= Week
X	= Special Code
ZZZZZZ-ZZ	= Lot Number

## **Packing Option**

Part Number	Marking	Packing Mode	M.O.Q
LSIC2SD065D16A	SIC2SD065D16	Tape and Reel	800



#### **TO-263 Carrier Reel Specifications**



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